NSN 5961-01-200-1513

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-200-1513 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 180.0 collector to emitter voltage/static/base open and 180.0 collector to base voltage, dc and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 30.00 amperes source cutoff current and 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 1.8 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**